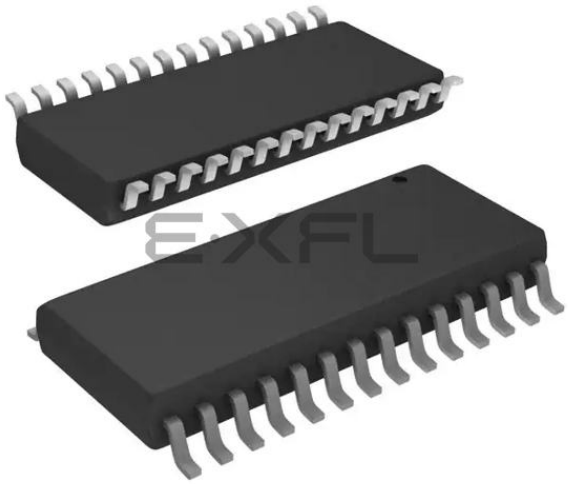

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Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	PIC
Core Size	8-Bit
Speed	20MHz
Connectivity	I²C, LINbus, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, POR, PWM, WDT
Number of I/O	25
Program Memory Size	28KB (16K x 14)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	1K x 8
Voltage - Supply (Vcc/Vdd)	2.3V ~ 5.5V
Data Converters	A/D 17x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	28-SOIC (0.295", 7.50mm Width)
Supplier Device Package	28-SOIC
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic16f1518-i-so

FIGURE 2-2: 28-PIN UQFN DIAGRAM FOR PIC16(L)F1512, PIC16(L)F1513, PIC16(L)F1516 AND PIC16(L)F1518

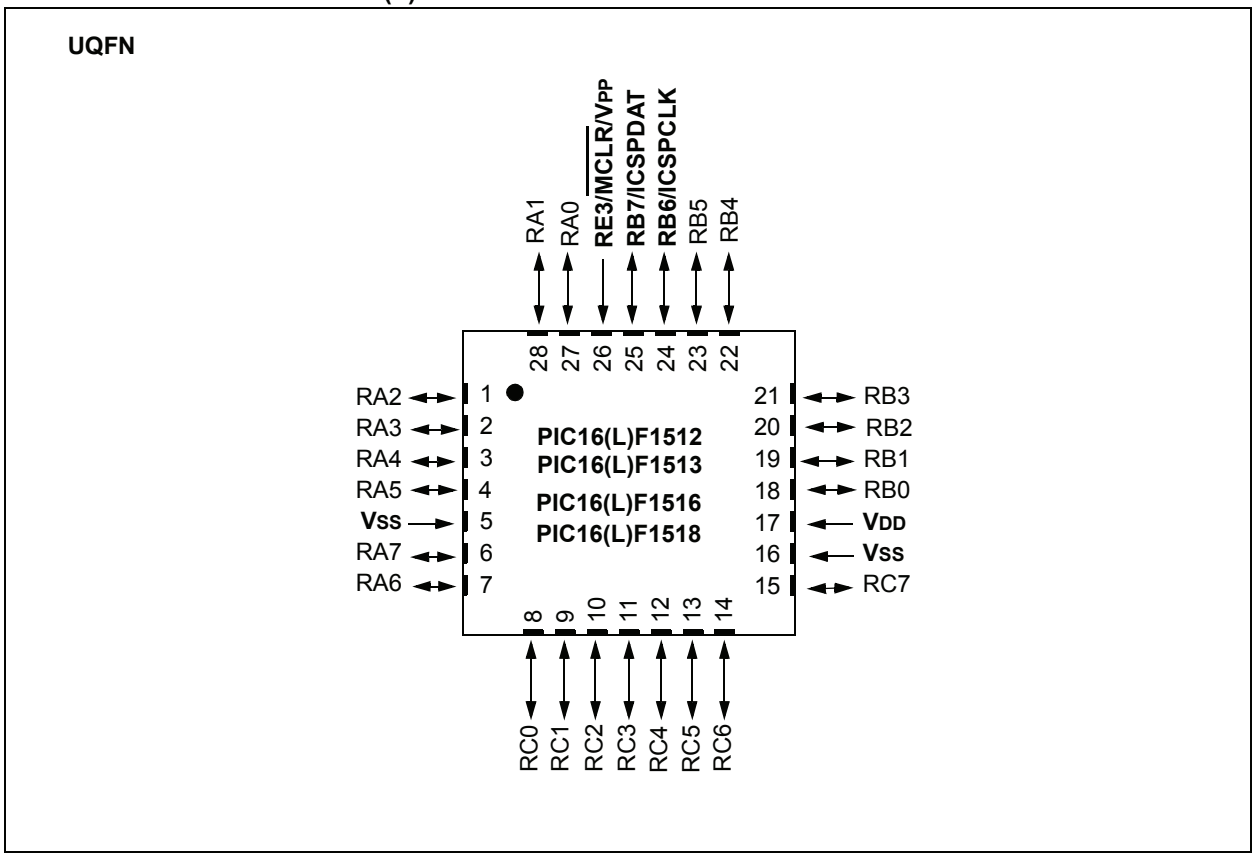


FIGURE 2-3: 40-PIN PDIP DIAGRAM FOR PIC16(L)F1517 AND PIC16(L)F1519

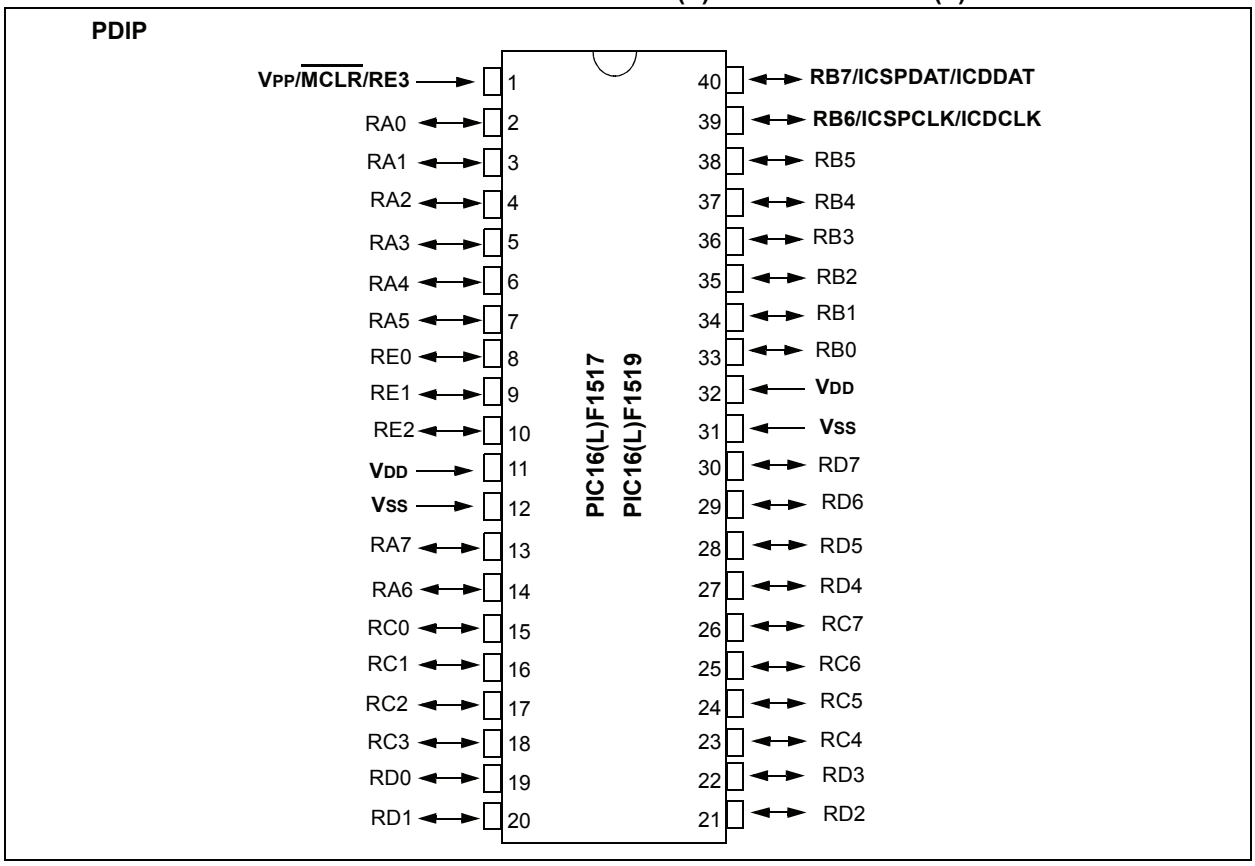


FIGURE 2-4: 40-PIN UQFN DIAGRAM FOR PIC16(L)F1517 AND PIC16(L)F1519

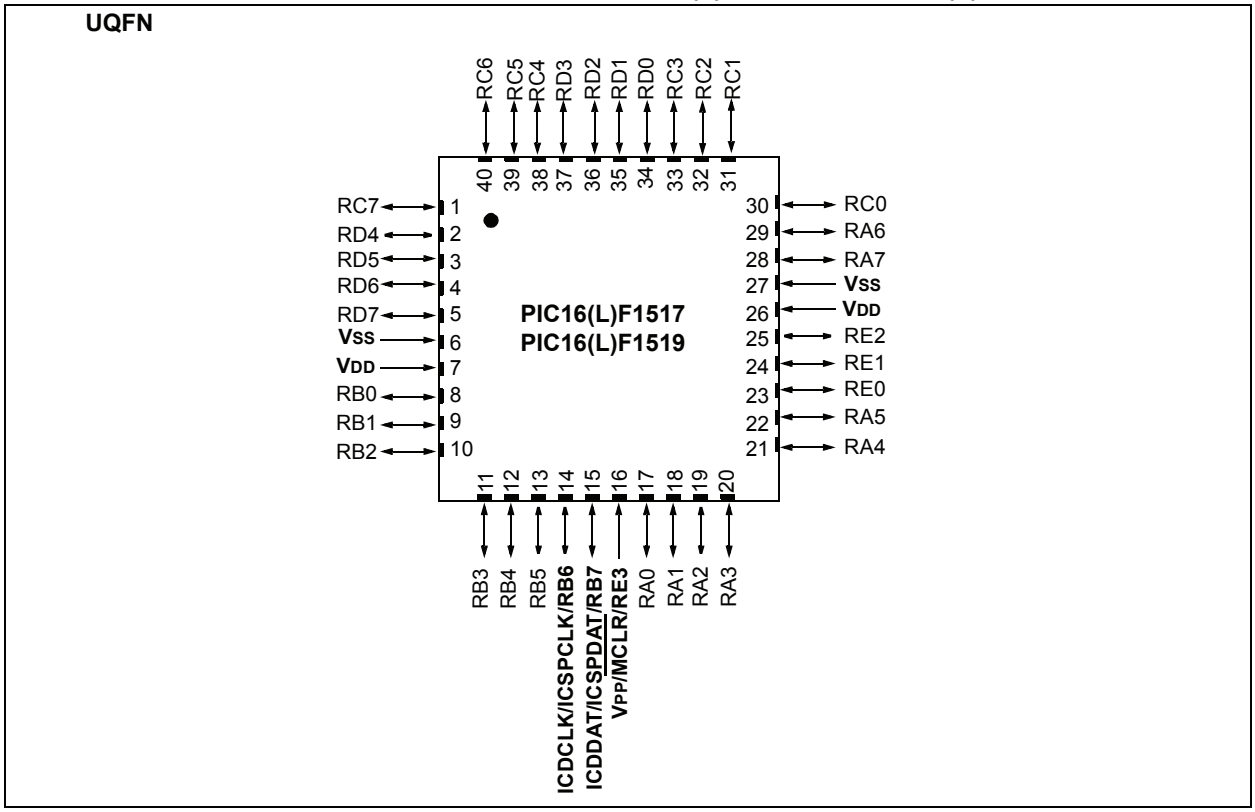
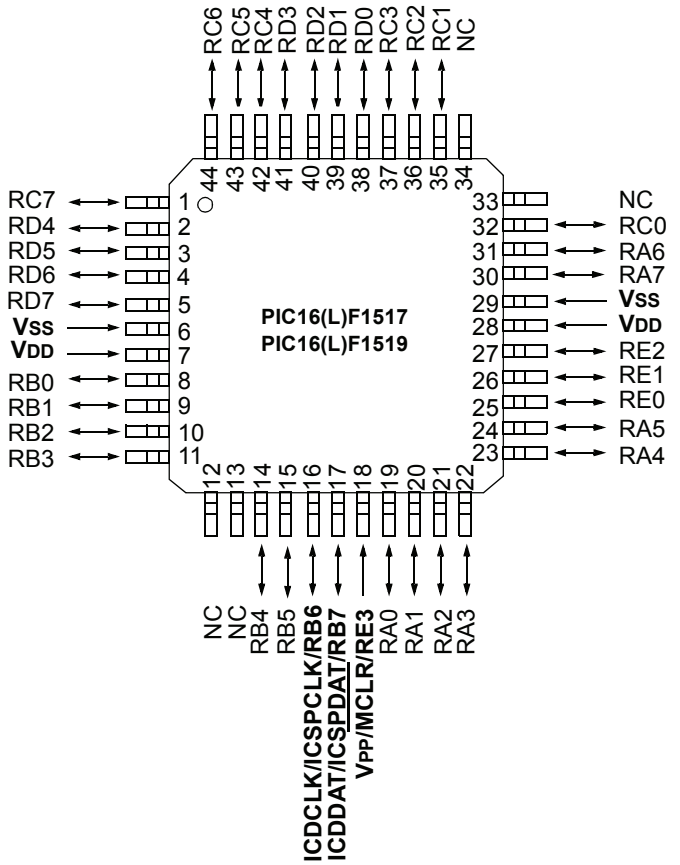


FIGURE 2-5: 44-PIN TQFP DIAGRAM FOR PIC16(L)F1517 AND PIC16(L)F1519

TQFP



3.0 MEMORY MAP

The memory for the PIC16(L)F151X/152X devices is broken into two sections: program memory and configuration memory. Only the size of the program memory changes between devices, the configuration memory remains the same.

FIGURE 3-1: PIC16(L)F1512 PROGRAM MEMORY MAPPING

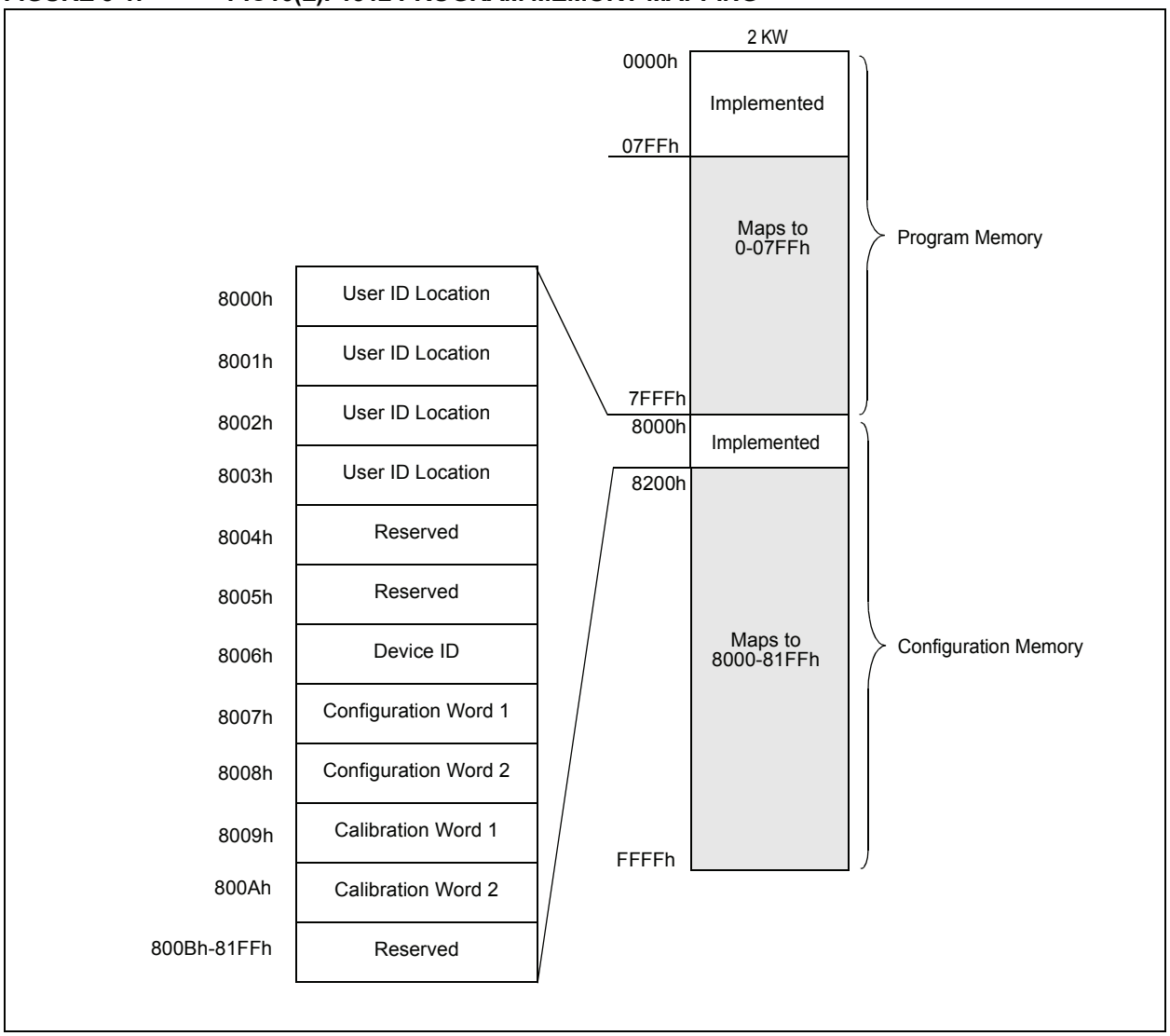


FIGURE 3-4: PIC16(L)F1527, PIC16(L)F1518 AND PIC16(L)F1519 PROGRAM MEMORY MAPPING

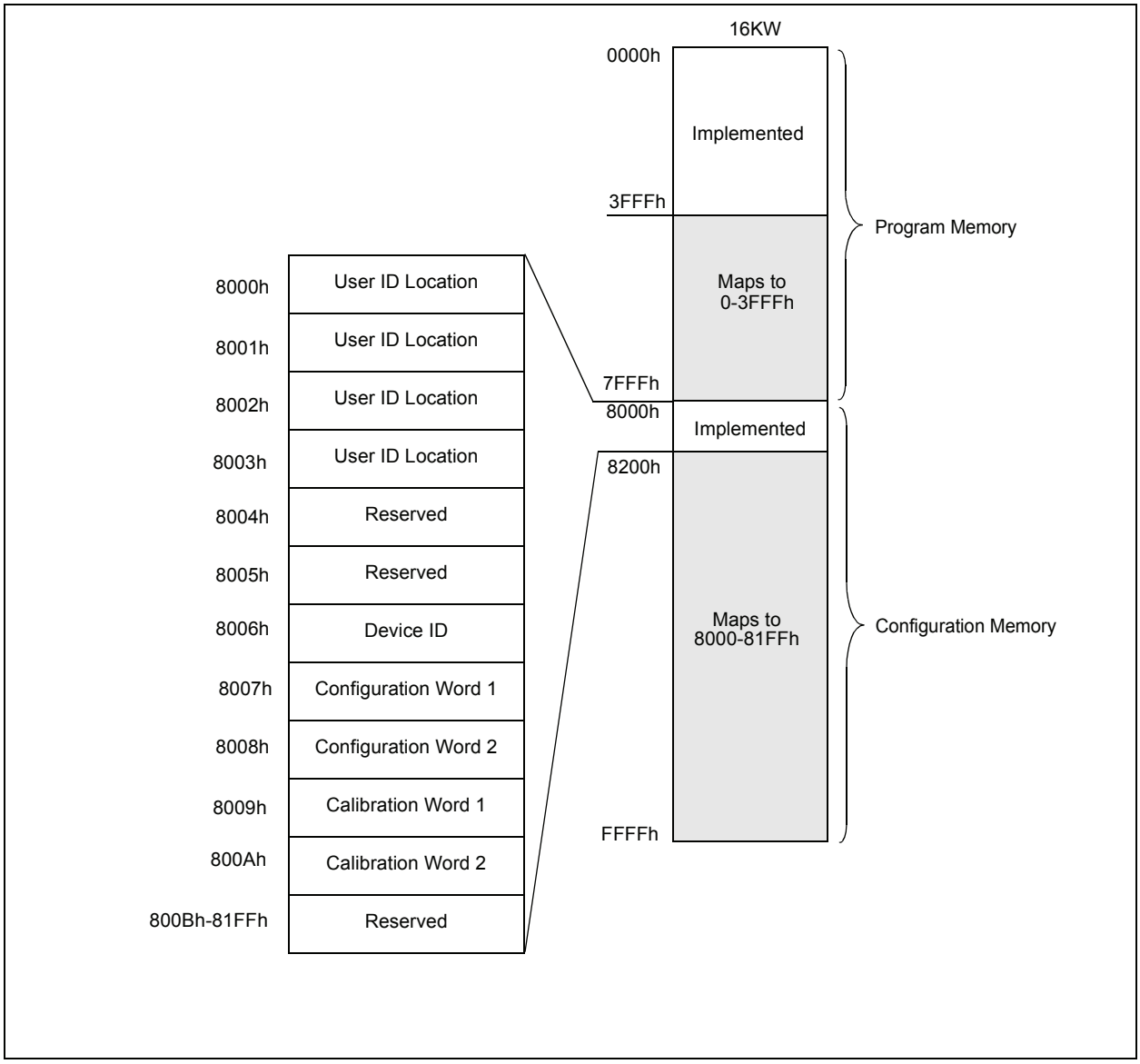


TABLE 3-1: DEVICE ID VALUES

DEVICE	DEVICE ID VALUES	
	DEV	REV
PIC16F1527	0001 0101 101	x xxxx
PIC16F1526	0001 0101 100	x xxxx
PIC16LF1527	0001 0101 111	x xxxx
PIC16LF1526	0001 0101 110	x xxxx
PIC16F1519	0001 0110 111	x xxxx
PIC16F1518	0001 0110 110	x xxxx
PIC16F1517	0001 0110 101	x xxxx
PIC16F1516	0001 0110 100	x xxxx
PIC16F1513	0001 0110 010	x xxxx
PIC16F1512	0001 0111 000	x xxxx
PIC16LF1519	0001 0111 111	x xxxx
PIC16LF1518	0001 0111 110	x xxxx
PIC16LF1517	0001 0111 101	x xxxx
PIC16LF1516	0001 0111 100	x xxxx
PIC16LF1513	0001 0111 010	x xxxx
PIC16LF1512	0001 0111 001	x xxxx

3.3 Configuration Words

There are two Configuration Words, Configuration Word 1 (8007h) and Configuration Word 2 (8008h). The individual bits within these Configuration Words are used to enable or disable device functions such as the Brown-out Reset, code protection and Power-up Timer.

3.4 Calibration Words

The internal calibration values are factory calibrated and stored in Calibration Words 1 and 2 (8009h, 800Ah).

The Calibration Words do not participate in erase operations. The device can be erased without affecting the Calibration Words.

REGISTER 3-2: CONFIGURATION WORD 1

R/P-1	R/P-1	R/P-1	R/P-1	R/P-1	U-1
FCMEN	IESO	$\overline{\text{CLKOUTEN}}$	BOREN<1:0>		—
bit 13					bit 8

R/P-1	R/P-1	R/P-1	R/P-1	R/P-1	R/P-1	R/P-1	R/P-1
$\overline{\text{CP}}$	MCLRE	$\overline{\text{PWRTE}}$	WDTE<1:0>		FOSC<2:0>		
bit 7							bit 0

Legend:		
R = Readable bit	P = Programmable bit	U = Unimplemented bit, read as '1'
'0' = Bit is cleared	'1' = Bit is set	-n = Value when blank or after Bulk Erase

bit 13 **FCMEN:** Fail-Safe Clock Monitor Enable bit
1 = Fail-Safe Clock Monitor is enabled
0 = Fail-Safe Clock Monitor is disabled

bit 12 **IESO:** Internal External Switchover bit
1 = Internal/External Switchover mode is enabled
0 = Internal/External Switchover mode is disabled

bit 11 **$\overline{\text{CLKOUTEN}}$:** Clock Out Enable bit
1 = CLKOUT function is disabled. I/O or oscillator function on CLKOUT pin.
0 = CLKOUT function is enabled on CLKOUT pin

bit 10-9 **BOREN<1:0>:** Brown-out Reset Enable bits(1)
11 = BOR enabled
10 = BOR enabled during operation and disabled in Sleep
01 = BOR controlled by SBOREN bit of the PCON register
00 = BOR disabled

bit 8 **Unimplemented:** Read as '1'

bit 7 **$\overline{\text{CP}}$:** Code Protection bit(2)
1 = Program memory code protection is disabled
0 = Program memory code protection is enabled

bit 6 **MCLRE:** $\overline{\text{MCLR}}$/VPP Pin Function Select bit
If LVP bit = 1:
This bit is ignored.
If LVP bit = 0:
1 = $\overline{\text{MCLR}}$/VPP pin function is $\overline{\text{MCLR}}$; Weak pull-up enabled.
0 = $\overline{\text{MCLR}}$/VPP pin function is digital input; $\overline{\text{MCLR}}$ internally disabled; Weak pull-up under control of WPUA register.

bit 5 **$\overline{\text{PWRTE}}$:** Power-up Timer Enable bit(1)
1 = PWRT disabled
0 = PWRT enabled

bit 4-3 **WDTE<1:0>:** Watchdog Timer Enable bit
11 = WDT enabled
10 = WDT enabled while running and disabled in Sleep
01 = WDT controlled by the SWDTEN bit in the WDTCON register
00 = WDT disabled

bit 2-0 **FOSC<2:0>:** Oscillator Selection bits
111 = ECH: External Clock, High-Power mode: on CLKIN pin
110 = ECM: External Clock, Medium-Power mode: on CLKIN pin
101 = ECL: External Clock, Low-Power mode: on CLKIN pin
100 = INTOSC oscillator: I/O function on OSC1 pin
011 = EXTRC oscillator: RC function on OSC1 pin
010 = HS oscillator: High-speed crystal/resonator on OSC2 pin and OSC1 pin
001 = XT oscillator: Crystal/resonator on OSC2 pin and OSC1 pin
000 = LP oscillator: Low-power crystal on OSC2 pin and OSC1 pin

Note 1: Enabling Brown-out Reset does not automatically enable Power-up Timer.
2: The entire program memory will be erased when the code protection is turned off.

REGISTER 3-3: CONFIGURATION WORD 2

R/P-1	R/P-1	R/P-1	R/P-1	R/P-1	U-1
LVP	$\overline{\text{DEBUG}}$	$\overline{\text{LPBOR}}$	BORV	STVREN	—
bit 13					bit 8

U-1	U-1	U-1	R/P-1	U-1	U-1	R/P-1	R/P-1
—	—	—	$\overline{\text{VCAPEN}}$(2)	—	—	WRT<1:0>	
bit 7							bit 0

Legend:		
R = Readable bit	P = Programmable bit	U = Unimplemented bit, read as '1'
'0' = Bit is cleared	'1' = Bit is set	-n = Value when blank or after Bulk Erase

bit 13 **LVP:** Low-Voltage Programming Enable bit(1)
1 = Low-voltage programming enabled
0 = HV on $\overline{\text{MCLR}}$/VPP must be used for programming

bit 12 **$\overline{\text{DEBUG}}$:** In-Circuit Debugger Mode bit
1 = In-Circuit Debugger disabled, ICSPCLK and ICSPDAT are general purpose I/O pins
0 = In-Circuit Debugger enabled, ICSPCLK and ICSPDAT are dedicated to the debugger

bit 11 **$\overline{\text{LPBOR}}$:** Low-Power BOR
1 = Low-Power BOR is disabled
0 = Low-Power BOR is enabled

bit 10 **BORV:** Brown-out Reset Voltage Selection bit
1 = Brown-out Reset voltage (VBOR), low trip point selected
0 = Brown-out Reset voltage (VBOR), high trip point selected

bit 9 **STVREN:** Stack Overflow/Underflow Reset Enable bit
1 = Stack Overflow or Underflow will cause a Reset
0 = Stack Overflow or Underflow will not cause a Reset

bit 8-5 **Unimplemented:** Read as '1'

bit 4 **$\overline{\text{VCAPEN}}$:** Voltage Regulator Capacitor Enable bits(1)
0 = VCAP functionality is enabled on VCAP pin
1 = All VCAP pin functions are disabled

bit 3-2 **Unimplemented:** Read as '1'

bit 1-0 **WRT<1:0>:** Flash Memory Self-Write Protection bits
2 kW Flash memory (PIC16(L)F1512):
11 = Write protection off
10 = 000h to 1FFh write-protected, 200h to 7FFh may be modified by PMCON control
01 = 000h to FFFh write-protected, 400h to 7FFh may be modified by PMCON control
00 = 000h to 7FFh write-protected, no addresses may be modified by PMCON control
4 kW Flash memory (PIC16(L)F1513):
11 = Write protection off
10 = 000h to 1FFh write-protected, 200h to FFFh may be modified by PMCON control
01 = 000h to 7FFh write-protected, 800h to FFFh may be modified by PMCON control
00 = 000h to FFFh write-protected, no addresses may be modified by PMCON control
8 kW Flash memory (PIC16F/LF1516/1517/1526):
11 = Write protection off
10 = 000h to 1FFh write-protected, 200h to 1FFFh may be modified by PMCON control
01 = 000h to FFFh write-protected, 1000h to 1FFFh may be modified by PMCON control
00 = 000h to 1FFFh write-protected, no addresses may be modified by PMCON control
16 kW Flash memory (PIC16F/LF1518/1519/1527):
11 = Write protection off
10 = 000h to 1FFh write-protected, 200h to 3FFFh may be modified by PMCON control
01 = 000h to 1FFFh write-protected, 2000h to 3FFFh may be modified by PMCON control
00 = 000h to 3FFFh write-protected, no addresses may be modified by PMCON control

Note 1: The LVP bit cannot be programmed to '0' when Programming mode is entered via LVP.
2: Applies to PIC16F151X/152X devices only. On PIC16LF151X/152X, the $\overline{\text{VCAPEN}}$ bit is unimplemented.

4.3 Program/Verify Commands

The PIC16(L)F151X/152X implements 10 programming commands; each six bits in length. The commands are summarized in Table 4-1.

Commands that have data associated with them are specified to have a minimum delay of TDLY between the command and the data. After this delay 16 clocks are required to either clock in or clock out the 14-bit data word. The first clock is for the Start bit and the last clock is for the Stop bit.

TABLE 4-1: COMMAND MAPPING

Command	Mapping							Data/Note
	Binary (MSb … LSb)						Hex	
Load Configuration	x	0	0	0	0	0	00h	0, data (14), 0
Load Data For Program Memory	x	0	0	0	1	0	02h	0, data (14), 0
Read Data From Program Memory	x	0	0	1	0	0	04h	0, data (14), 0
Increment Address	x	0	0	1	1	0	06h	—
Reset Address	x	1	0	1	1	0	16h	—
Begin Internally Timed Programming	x	0	1	0	0	0	08h	—
Begin Externally Timed Programming	x	1	1	0	0	0	18h	—
End Externally Timed Programming	x	0	1	0	1	0	0Ah	—
Bulk Erase Program Memory	x	0	1	0	0	1	09h	Internally Timed
Row Erase Program Memory	x	1	0	0	0	1	11h	Internally Timed

4.3.1 LOAD CONFIGURATION

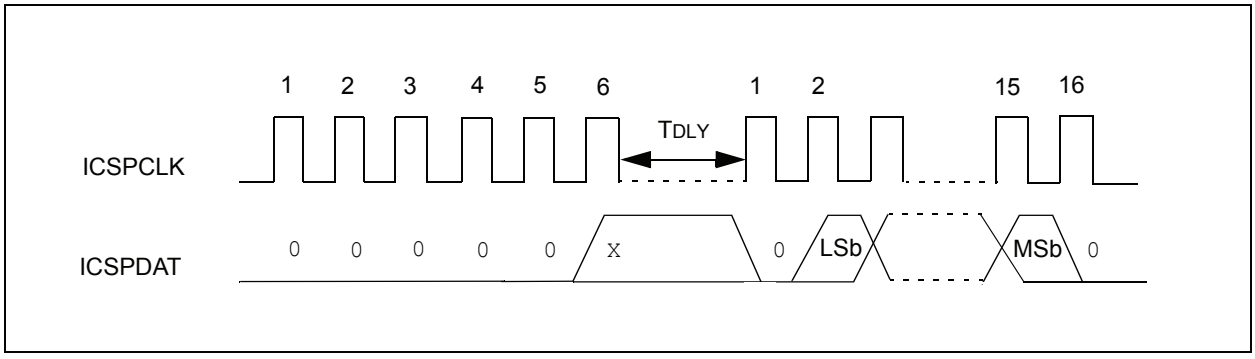
The Load Configuration command is used to access the configuration memory (User ID Locations, Configuration Words, Calibration Words). The Load Configuration command sets the address to 8000h and loads the data latches with one word of data (see Figure 4-1).

After issuing the Load Configuration command, use the Increment Address command until the proper address to be programmed is reached. The address is then programmed by issuing either the Begin Internally Timed Programming or Begin Externally Timed Programming command.

Note: Externally timed writes are not supported for Configuration and Calibration bits. Any externally timed write to the Configuration or Calibration Word will have no effect on the targeted word.

The only way to get back to the program memory (address 0) is to exit Program/Verify mode or issue the Reset Address command after the configuration memory has been accessed by the Load Configuration command.

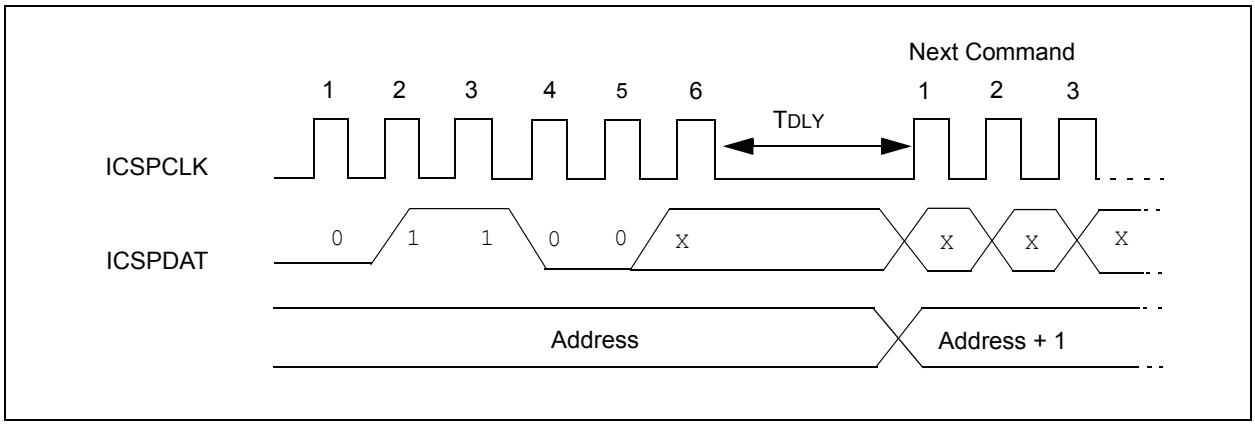
FIGURE 4-1: LOAD CONFIGURATION



4.3.4 INCREMENT ADDRESS

The address is incremented when this command is received. It is not possible to decrement the address. To reset this counter, the user must use the Reset Address command or exit Program/Verify mode and re-enter it. If the address is incremented from address 7FFFh, it will wrap-around to location 0000h. If the address is incremented from FFFFh, it will wrap-around to location 8000h.

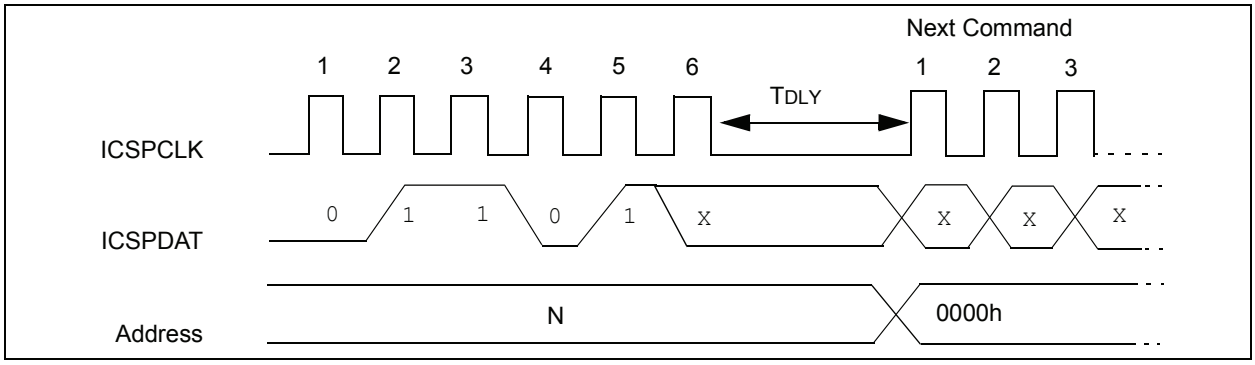
FIGURE 4-4: INCREMENT ADDRESS



4.3.5 RESET ADDRESS

The Reset Address command will reset the address to 0000h, regardless of the current value. The address is used in program memory or the configuration memory.

FIGURE 4-5: RESET ADDRESS

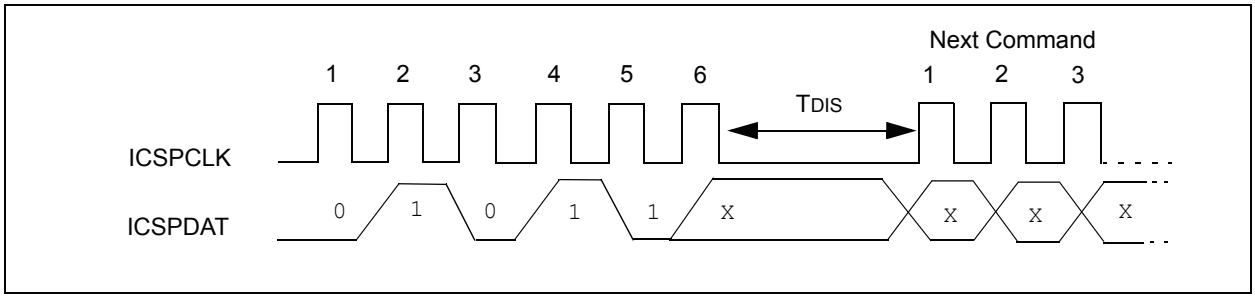


4.3.8 END EXTERNALLY TIMED PROGRAMMING

This command is required after a Begin Externally Timed Programming command is given. This command must be sent within the time window specified by TPEXT after the Begin Externally Timed Programming command is sent.

After sending the End Externally Timed Programming command, an additional delay (TDIS) is required before sending the next command. This delay is longer than the delay ordinarily required between other commands (see Figure 4-8).

FIGURE 4-8: END EXTERNALLY TIMED PROGRAMMING



4.3.9 BULK ERASE PROGRAM MEMORY

The Bulk Erase Program Memory command performs two different functions dependent on the current state of the address.

Address 0000h-7FFFh:

- Program Memory is erased
- Configuration Words are erased

Address 8000h-8008h:

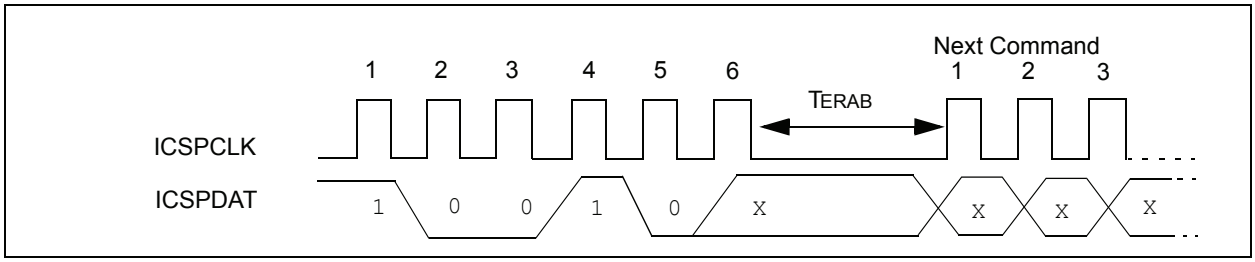
- Program Memory is erased
- Configuration Words are erased
- User ID Locations are erased

A Bulk Erase Program Memory command should not be issued when the address is greater than 8008h.

After receiving the Bulk Erase Program Memory command the erase will not complete until the time interval, TERAB, has expired.

Note:	The code protection Configuration bit ($\overline{CP}$) has no effect on the Bulk Erase Program Memory command.

FIGURE 4-9: BULK ERASE PROGRAM MEMORY



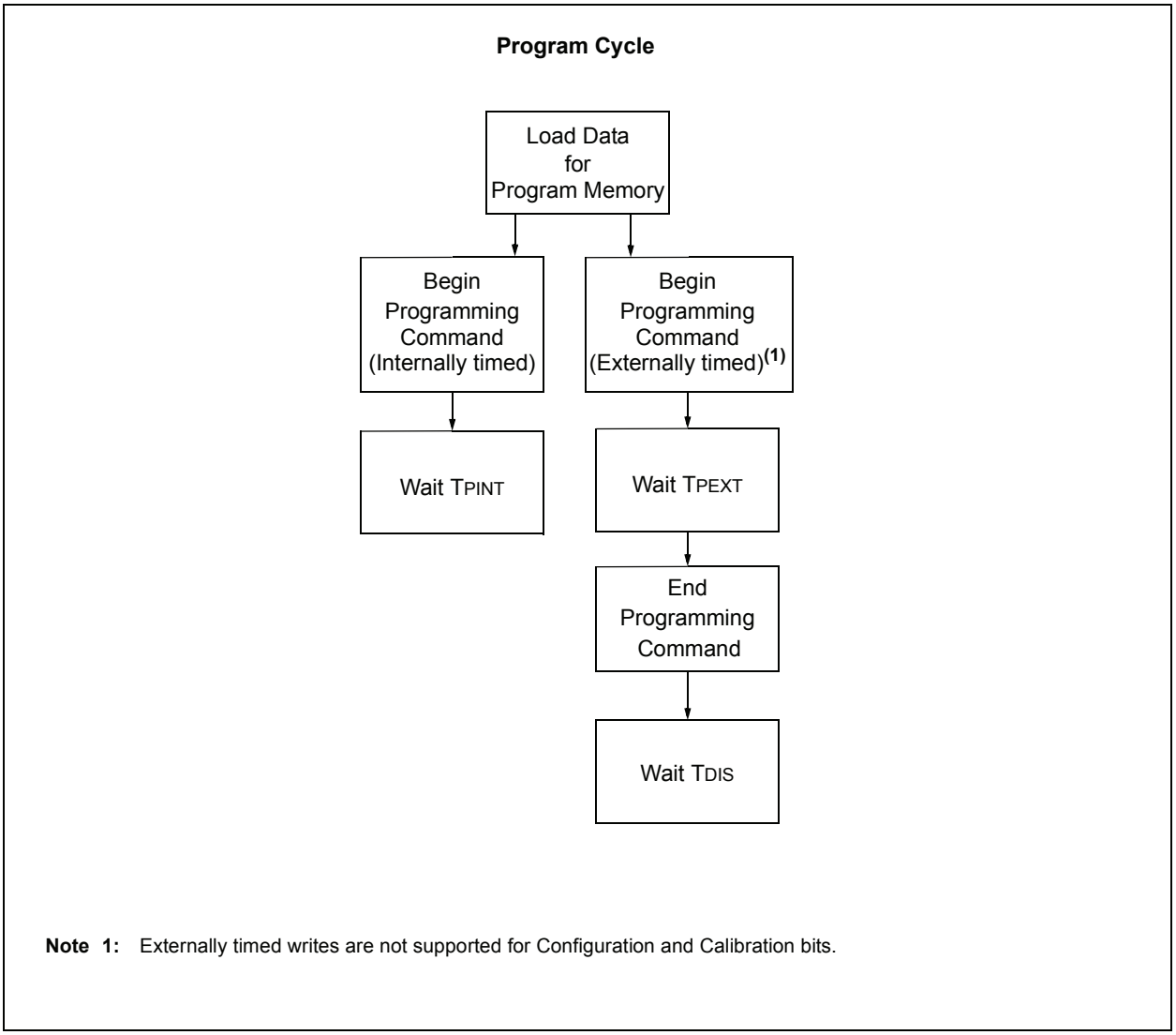
5.0 PROGRAMMING ALGORITHMS

The devices use internal latches to temporarily store the 14-bit words used for programming. Refer to Table 4-2 for specific latch information. The data latches allow the user to write the program words with a single Begin Externally Timed Programming or Begin Internally Timed Programming command. The Load Program Data or the Load Configuration command is used to load a single data latch. The data latch will hold the data until the Begin Externally Timed Programming or Begin Internally Timed Programming command is given.

The data latches are aligned with the LSbs of the address. The PC's address at the time the Begin Externally Timed Programming or Begin Internally Timed Programming command is given will determine which location(s) in memory are written. Writes cannot cross the physical boundary. For example, with the PIC16F1527, attempting to write from address 0002h-0009h will result in data being written to 0008h-000Fh.

If more than the maximum number of data latches are written without a Begin Externally Timed Programming or Begin Internally Timed Programming command, the data in the data latches will be overwritten. The following figures show the recommended flowcharts for programming.

FIGURE 5-3: ONE-WORD PROGRAM CYCLE



Note 1: Externally timed writes are not supported for Configuration and Calibration bits.

FIGURE 5-4: MULTIPLE-WORD PROGRAM CYCLE

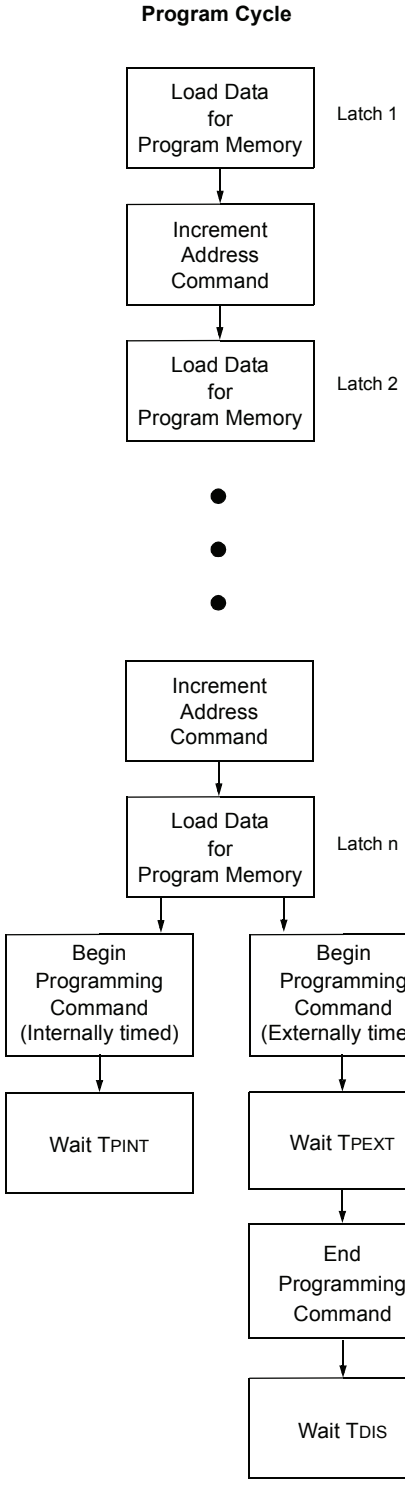
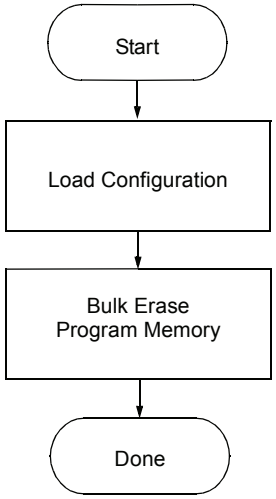


FIGURE 5-6: ERASE FLOWCHART



Note: This sequence does not erase the Calibration Words.

7.3 Checksum Computation

The checksum is calculated by two different methods dependent on the setting of the $\overline{CP}$ Configuration bit.

TABLE 7-1: CONFIGURATION WORD MASK VALUES

Device	Config. Word 1 Mask	Config. Word 2 Mask
PIC16F1512	3EFFh	3E13h
PIC16F1513	3EFFh	3E13h
PIC16F1516	3EFFh	3E13h
PIC16F1517	3EFFh	3E13h
PIC16F1518	3EFFh	3E13h
PIC16F1519	3EFFh	3E13h
PIC16LF1512	3EFFh	3E03h
PIC16LF1513	3EFFh	3E03h
PIC16LF1516	3EFFh	3E03h
PIC16LF1517	3EFFh	3E03h
PIC16LF1518	3EFFh	3E03h
PIC16LF1519	3EFFh	3E03h
PIC16F1526	3EFFh	3E13h
PIC16F1527	3EFFh	3E13h
PIC16LF1526	3EFFh	3E03h
PIC16LF1527	3EFFh	3E03h

7.3.1 PROGRAM CODE PROTECTION DISABLED

With the program code protection disabled, the checksum is computed by reading the contents of the PIC16(L)F151X/152X program memory locations and adding up the program memory data starting at address 0000h, up to the maximum user addressable location. Any Carry bit exceeding 16 bits are ignored. Additionally, the relevant bits of the Configuration Words are added to the checksum. All unimplemented Configuration bits are masked to '0'.

EXAMPLE 7-4: CHECKSUM COMPUTED WITH PROGRAM CODE PROTECTION ENABLED PIC16LF1527, 00AAh AT FIRST AND LAST ADDRESS

PIC16LF1527	Configuration Word 1(2)	3F7Fh
	Configuration Word 1 mask(3)	3EFFh
	Configuration Word 2(2)	3FFFh
	Configuration Word 2 mask(3), (5)	3E03h
	User ID (8000h)(1)	000Eh
	User ID (8001h)(1)	0008h
	User ID (8002h)(1)	0005h
	User ID (8003h)(1)	0008h
	Sum of User IDs(4)	= (000Eh and 000Fh) << 12 + (0008h and 000Fh) << 8 + (0005h and 000Fh) << 4 + (0008h and 000Fh) = E000h + 0800h + 0050h + 0008h = E858h
	Checksum	= (3F7Fh and 3EFFh) + (3FFFh and 3E03h) + Sum of User IDs = 3E7Fh +3E03h + E858h = 64DAh

Note 1: User ID values in this example are random values.

2: Configuration Word 1 and 2 = all bits are '1' except the code-protect enable bit.

3: Configuration Word 1 and 2 Mask = all Configuration Word bits are set to '1', except for unimplemented bits which read '0'.

4: << = shift left, thus the LSb of the first user ID value is the MSb of the sum of user IDs and so on, until the LSb of the last user ID value becomes the LSb of the sum of user IDs.

5: On the PIC16LF1527 device, the $\overline{\text{VCAPEN}}$ bit is not implemented in Configuration Word 2; thus, all unimplemented bits are '0'.

8.0 ELECTRICAL SPECIFICATIONS

Refer to device specific data sheet for absolute maximum ratings.

TABLE 8-1: AC/DC CHARACTERISTICS TIMING REQUIREMENTS FOR PROGRAM/VERIFY MODE

AC/DC CHARACTERISTICS			Standard Operating Conditions Production tested at 25°C				
Sym.	**Characteristics**		**Min.**	**Typ.**	**Max.**	**Units**	**Conditions/Comments**
Supply Voltages and Currents							
V_{DD}	Supply Voltage (V_{DDMIN}, V_{DDMAX})	PIC16F151X PIC16F152X	2.3	—	5.5	V	
		PIC16LF151X PIC16LF152X	1.8	—	3.6	V	
V_{PEW}	Read/Write and Row Erase operations		V_{DDMIN}	—	V_{DDMAX}	V	
V_{PBE}	Bulk Erase operations		2.7	—	V_{DDMAX}	V	
I_{DDI}	Current on V_{DD}, Idle		—	—	1.0	mA	
I_{DDP}	Current on V_{DD}, Programming		—	—	3.0	mA	
	V_{PP}						
I_{PP}	Current on $\overline{MCLR}/V_{PP}$		—	—	600	μA	
V_{IHH}	High voltage on $\overline{MCLR}/V_{PP}$ for Program/Verify mode entry		8.0	—	9.0	V	
T_{VHHR}	$\overline{MCLR}$ rise time (V_{IL} to V_{IHH}) for Program/Verify mode entry		—	—	1.0	μs	
	I/O pins						
V_{IH}	(ICSPCLK, ICSPDAT, $\overline{MCLR}/V_{PP}$) input high level		0.8 V_{DD}	—	—	V	
V_{IL}	(ICSPCLK, ICSPDAT, $\overline{MCLR}/V_{PP}$) input low level		—	—	0.2 V_{DD}	V	
V_{OH}	ICSPDAT output high level		V_{DD}-0.7 V_{DD}-0.7 V_{DD}-0.7	—	—	V	I_{OH} = 3.5 mA, V_{DD} = 5V I_{OH} = 3 mA, V_{DD} = 3.3V I_{OH} = 2 mA, V_{DD} = 1.8V
V_{OL}	ICSPDAT output low level		—	—	V_{SS}+0.6 V_{SS}+0.6 V_{SS}+0.6	V	I_{OH} = 8 mA, V_{DD} = 5V I_{OH} = 6 mA, V_{DD} = 3.3V I_{OH} = 3 mA, V_{DD} = 1.8V
Programming Mode Entry and Exit							
T_{ENTS}	Programing mode entry setup time: ICSPCLK, ICSPDAT setup time before V_{DD} or $\overline{MCLR}$↑		100	—	—	ns	
T_{ENTH}	Programing mode entry hold time: ICSPCLK, ICSPDAT hold time after V_{DD} or $\overline{MCLR}$↑		250	—	—	μs	
Serial Program/Verify							
T_{CKL}	Clock Low Pulse Width		100	—	—	ns	
T_{CKH}	Clock High Pulse Width		100	—	—	ns	
T_{DS}	Data in setup time before clock↓		100	—	—	ns	
T_{DH}	Data in hold time after clock↓		100	—	—	ns	
T_{CO}	Clock↑ to data out valid (during a Read Data command)		0	—	80	ns	
T_{LZD}	Clock↓ to data low-impedance (during a Read Data command)		0	—	80	ns	
T_{HZD}	Clock↓ to data high-impedance (during a Read Data command)		0	—	80	ns	
T_{DLY}	Data input not driven to next clock input (delay required between command/data or command/command)		1.0	—	—	μs	
T_{ERAB}	Bulk Erase cycle time		—	—	5	ms	
T_{ERAR}	Row Erase cycle time		—	—	2.5	ms	

Note 1: Externally timed writes are not supported for Configuration and Calibration bits.

APPENDIX A: REVISION HISTORY

Revision A (08/2010)

Original release of this document.

Revision B (09/2011)

Added PIC16(L)F1512/1513 devices; Added new Figures 3-1 and 3-2; Updated Registers 3-1, 3-2 and 3-3 to new format; Updated Register 3-3 to add 2 kW and 4 kW Flash memory; Added Notes to Examples 7-1 to 7-4; Updated Table 8-1; Other minor corrections.

NOTES:

